

SOT-23 Formed SMD Package

BF840
BF841

SILICON PLANAR TRANSISTORS

N-P-N transistors

Marking

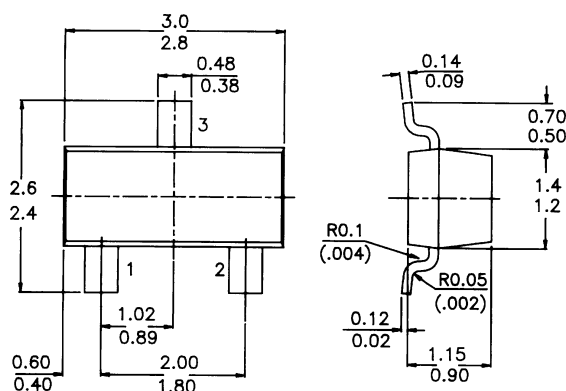
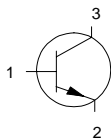
BF840 = NC

BF841 = ND

PACKAGE OUTLINE DETAILS ALL DIMENSIONS IN mm

Pin configuration

1 = BASE
2 = EMITTER
3 = COLLECTOR



ABSOLUTE MAXIMUM RATINGS

		BF840	BF841
Collector-base voltage (open emitter)	V_{CB0} max.	40	V
Collector-emitter voltage (open base)	V_{CE0} max.	40	V
Collector current (d.c.)	I_C max.	25	mA
Base current	I_B	4,5-15	8-28 mA
$I_C = 1$ mA; $V_{CE} = 10$ V			
Total power dissipation up to $T_{amb} = 25$ °C	P_{tot} max.	250	mW
Junction temperature	T_j max.	150	°C
Feedback capacitance at $f = 1$ MHz	C_{re} typ.	0,3	pF
$I_C = 1$ mA; $V_{CE} = 10$ V			

BF840
BF841

RATINGS (at $T_A = 25^\circ\text{C}$ unless otherwise specified)

Limiting values

Collector-base voltage (open emitter)	V_{CB0}	max.	40 V
Collector-emitter voltage (open base)	V_{CE0}	max.	40 V
Emitter-base voltage (open collector)	V_{EB0}	max.	4 V
Collector current (d.c.)	I_C	max.	25 mA
Total power dissipation up to $T_{amb} = 25^\circ\text{C}^*$	P_{tot}	max.	250 mW

Storage temperature

T_{stg} -55 to +150 °C

Junction temperature

T_j max. 150 °C

THERMAL RESISTANCE

From junction to ambient

$R_{th\ j-a}$ 500 K/W

CHARACTERISTICS

$T_j = 25^\circ\text{C}$ unless otherwise specified

Collector cut-off current

$I_E = 0$; $V_{CB} = 20\text{ V}$

I_{CBO} max. 100 nA

Base-emitter voltage

$I_C = 1\text{ mA}$; $V_{CE} = 10\text{ V}$

V_{BE} typ. 700 mV
650 to 740 mV

Base current

$I_C = 1\text{ mA}$; $V_{CE} = 10\text{ V}$

		BF840	BF841
I_B		4,5–15	8–28 mA
f_T	typ.	380	380 MHz
C_{re}	typ.	0,3	0,3 pF
F	typ.	1,5	2,0 dB

Transition frequency at $f = 100\text{ MHz}$

$I_C = 1\text{ mA}$; $V_{CE} = 10\text{ V}$

Feedback capacitance at $f = 1\text{ MHz}$

$I_C = 1\text{ mA}$; $V_{CE} = 10\text{ V}$

Noise figure

$I_C = 1\text{ mA}$; $V_{CE} = 10\text{ V}$;

$f = 0,2\text{ MHz}$; $R_S = 200\text{ }\Omega$

Disclaimer

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